NSN 5962-00-436-2167



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-00-436-2167 **Body Length:** Between 0.660 inches and 0.785 inches **Body Width:** Between 0.220 inches and 0.280 inches **Body Height:** Between 0.140 inches and 0.180 inches **Maximum Power Dissipation Rating:** 69.0 milliwatts **Operating Tempurature Range:** +0.0/+75.0 degrees celsius Storage Tempurature Range: -65.0/+175.0 degrees celsius **Features Provided:** Low power and monolithic and positive outputs and resettable and w/strobe and negative edge triggered **Inclosure Material: Plastic Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 8 input **Case Outline Source And Designator:** T0-116 joint electron device engineering council **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 5.5 volts power source **Time Rating Per Chacteristic:** 100.00 nanoseconds propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Terminal Type And Quantity:** 14 printed circuit Shelf Life: N/a

Demilitarization: Yes - demil/mli

Unit Of Measure:

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